



SCH1439

N-Channel Power MOSFET 30V, 3.5A, 72mΩ, Single SCH6

ON Semiconductor®
<http://onsemi.com>

Features

- ON-resistance $R_{DS(on)1}=55m\Omega$ (typ.)
- 4V drive
- Halogen free compliance
- Protection diode in

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

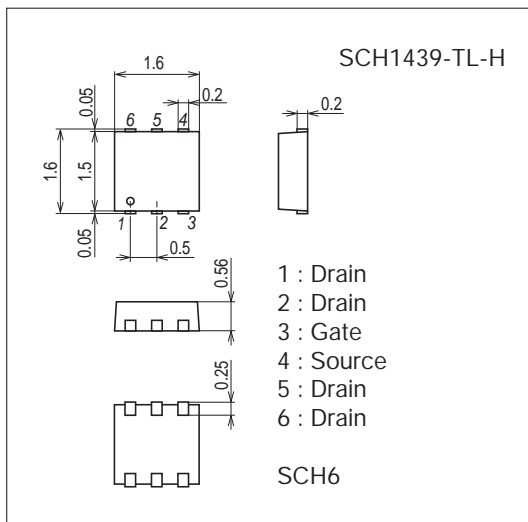
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		30	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		3.5	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	14	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² ×0.8mm)	1	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

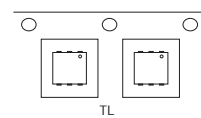
7028-002



Product & Package Information

- Package : SCH6
- JEITA, JEDEC : SOT-563
- Minimum Packing Quantity : 5,000 pcs./reel

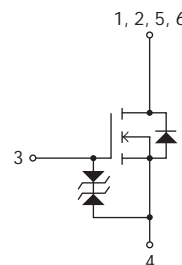
Packing Type : TL



Marking



Electrical Connection

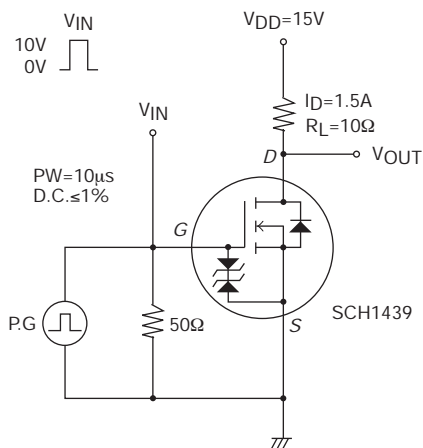


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Electrical Characteristics at Ta=25°C

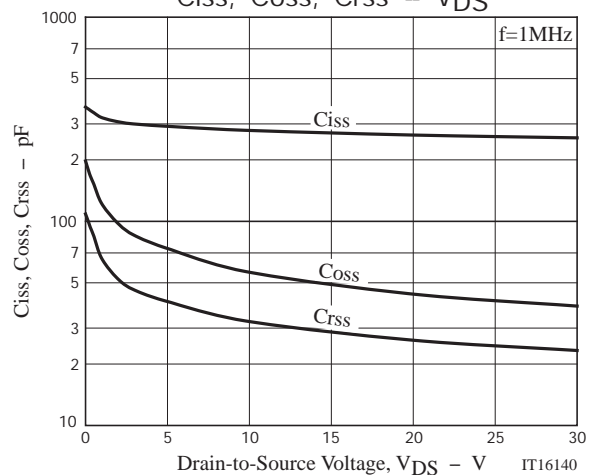
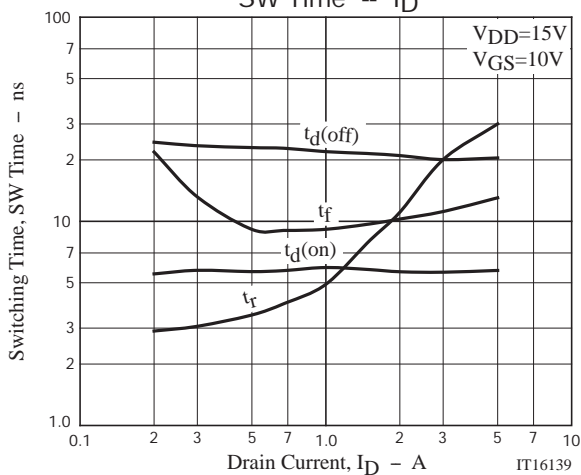
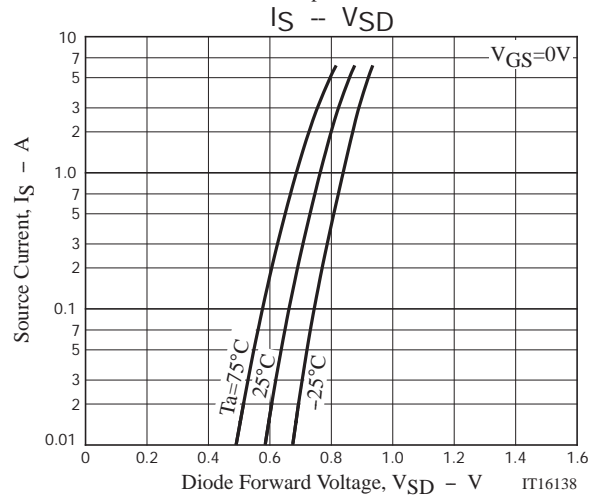
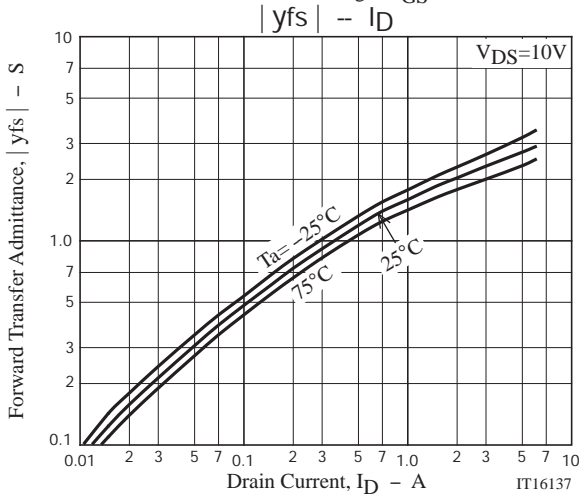
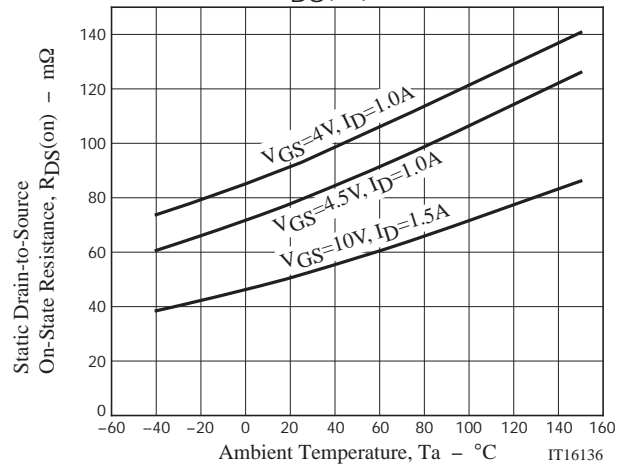
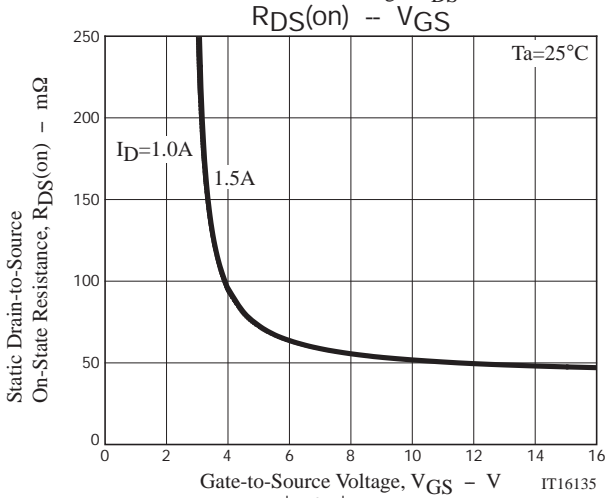
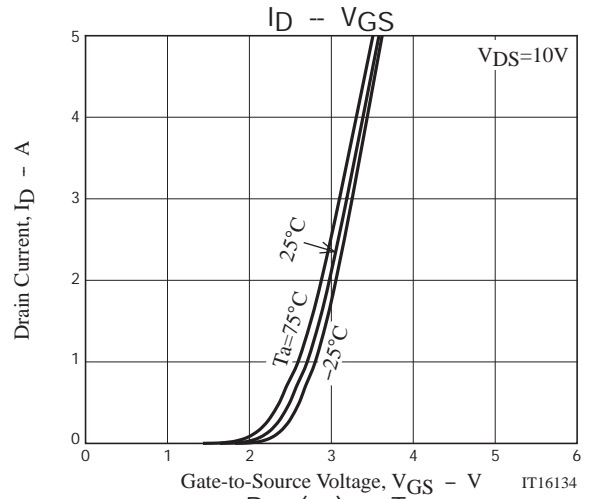
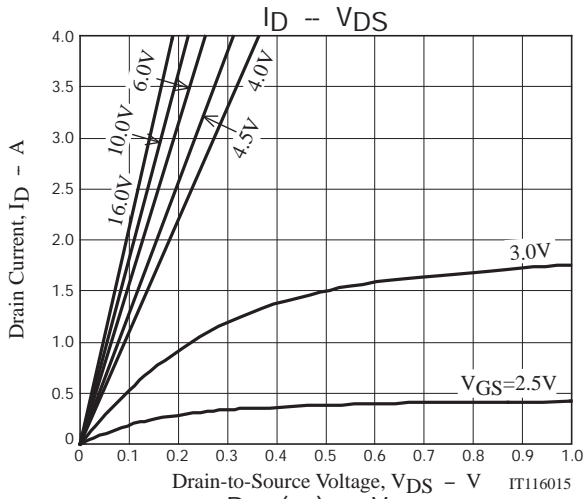
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	VDS=10V, ID=1.5A		1.8		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=1.5A, VGS=10V		55	72	mΩ
	RDS(on)2	ID=1A, VGS=4.5V		78	110	mΩ
	RDS(on)3	ID=1A, VGS=4V		91	128	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		280		pF
Output Capacitance	Coss			60		pF
Reverse Transfer Capacitance	Crss			30		pF
Turn-ON Delay Time	td(on)		See specified Test Circuit.		5.8	
Rise Time	tr			8.0		ns
Turn-OFF Delay Time	td(off)			21		ns
Fall Time	tf			9.7		ns
Total Gate Charge	Qg	VDS=15V, VGS=10V, ID=3.5A			5.6	
Gate-to-Source Charge	Qgs			1.2		nC
Gate-to-Drain "Miller" Charge	Qgd			0.8		nC
Diode Forward Voltage	VSD	IS=3.5A, VGS=0V		0.84	1.2	V

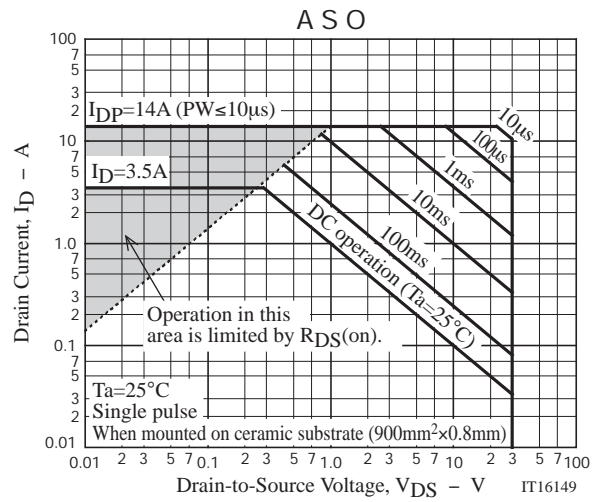
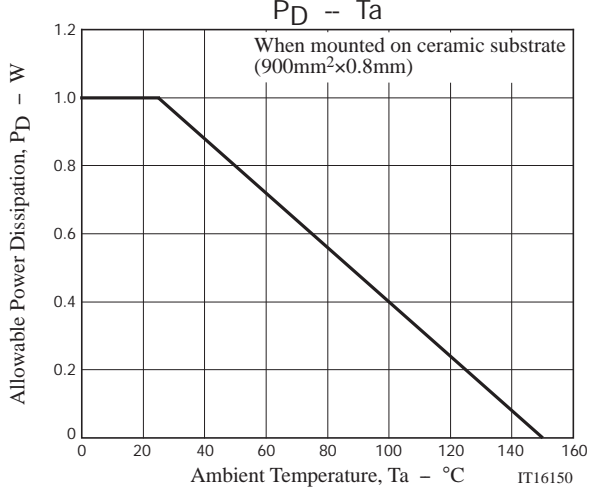
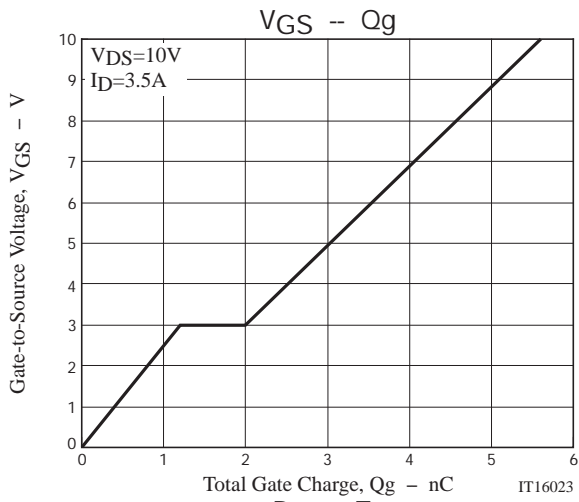
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
SCH1439-TL-H	SCH6	5,000pcs./reel	Pb Free and Halogen Free





Taping Specification

SCH1439-TL-H

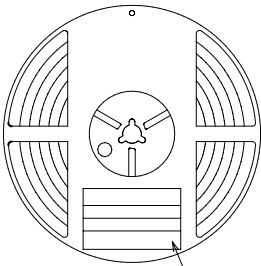
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
SCH6	SCH6	5,000	25,000	150,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

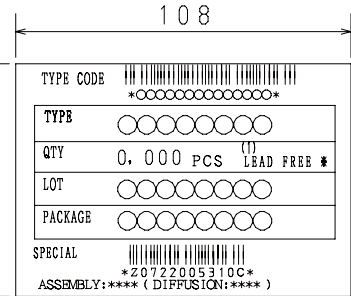
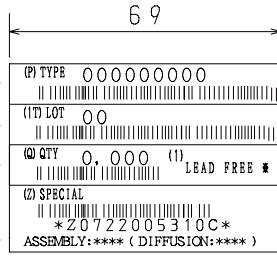
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No. →
LOT No. →
Quantity →
Origin →



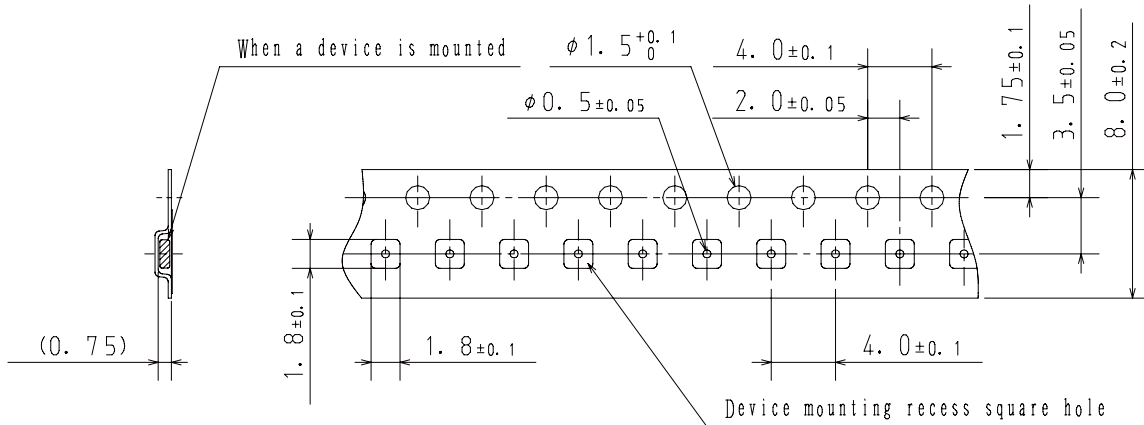
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

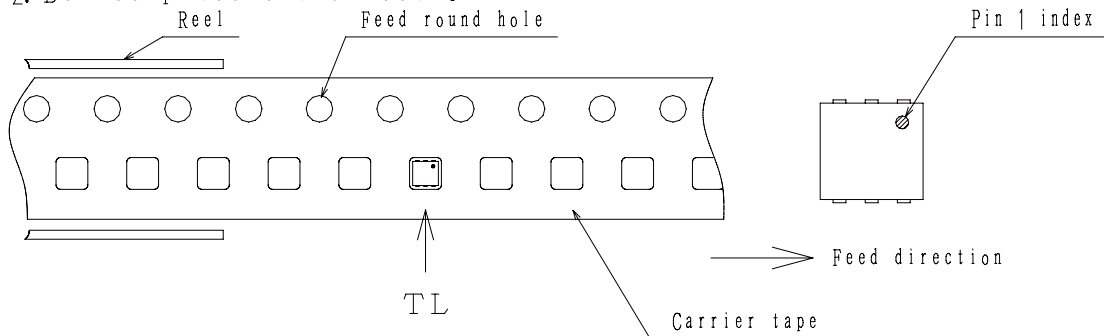
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



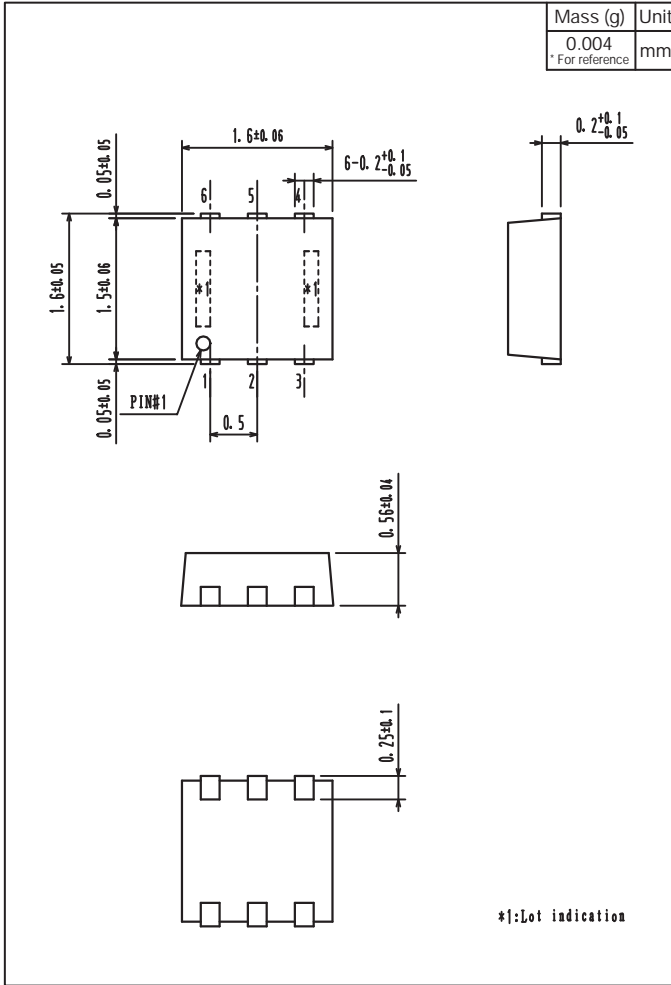
2-2. Device placement direction



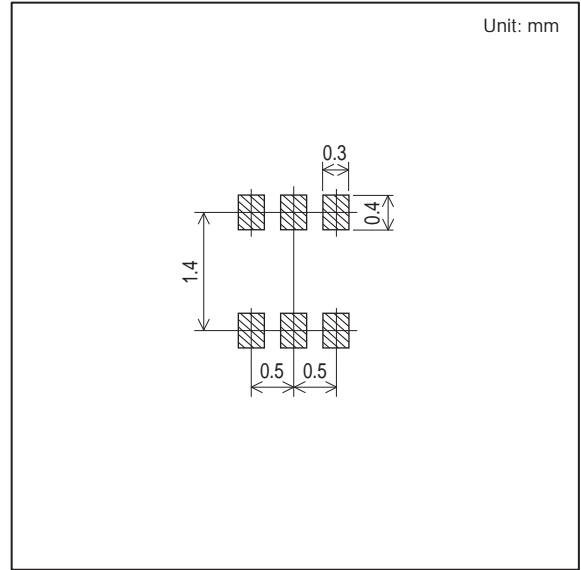
Those with pin 1 index on the feed hole side.....TL

SCH1439

Outline Drawing SCH1439-TL-H



Land Pattern Example



Note on usage : Since the SCH1439 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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